ONSEMI Video Amplifier

NE592

The NE592 is a monolithic, two-stage, differential output, wideband video amplifier. It offers fixed gains of 100 and 400 without external components and adjustable gains from 400 to 0 with one external resistor. The input stage has been designed so that with the addition of a few external reactive elements between the gain select terminals, the circuit can function as a high-pass, low-pass, or band-pass filter. This feature makes the circuit ideal for use as a video or pulse amplifier in communications, magnetic memories, display, video recorder systems, and floppy disk head amplifiers. Now available in an 8-pin version with fixed gain of 400 without external components and adjustable gain from 400 to 0 with one external resistor.

Features

- 120 MHz Unity Gain Bandwidth
- Adjustable Gains from 0 to 400
- Adjustable Pass Band
- No Frequency Compensation Required
- Wave Shaping with Minimal External Components
- MIL-STD Processing Available
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Floppy Disk Head Amplifier
- Video Amplifier
- Pulse Amplifier in Communications
- Magnetic Memory
- Video Recorder Systems

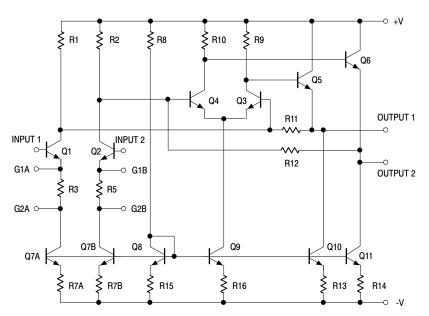
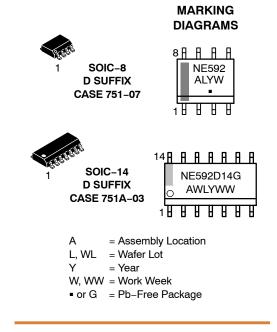


Figure 1. Block Diagram

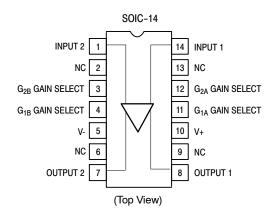


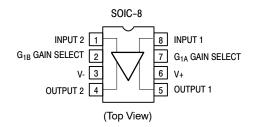
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 8.

PIN CONNECTIONS





MAXIMUM RATINGS (T_A = +25°C, unless otherwise noted.)

Rating	Symbol	Value	Unit
Supply Voltage	V _{CC}	±8.0	V
Differential Input Voltage	V _{IN}	±5.0	V
Common-Mode Input Voltage	V _{CM}	±6.0	V
Output Current	Ι _{ΟυΤ}	10	mA
Operating Ambient Temperature Range	T _A	0 to +70	°C
Operating Junction Temperature	TJ	150	°C
Storage Temperature Range	T _{STG}	65 to +150	°C
Maximum Power Dissipation, T _A = 25°C (Still Air) (Note 1) SOIC-14 Package SOIC-8 Package	P _{D MAX}	0.98 0.79	W
Thermal Resistance, Junction-to-Ambient SOIC-14 Package SOIC-8 Package	R _{θJA}	145 182	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Derate above 25°C at the following rates: SOIC-14 package at 6.9 mW/°C SOIC-8 package at 5.5 mW/°C

Characteristic	Test Conditions	Symbol	Min	Тур	Max	Unit
Differential Voltage Gain Gain 1 (Note 2) Gain 2 (Notes 3 and 4)	R _L = 2.0 kΩ, V _{OUT} = 3.0 V _{P-P}	A _{VOL}	250 80	400 100	600 120	V/V
Input Resistance Gain 1 (Note 2) Gain 2 (Notes 3 and 4)	$T_{A} = 25^{\circ}C$ $0^{\circ}C \le T_{A} \le 70^{\circ}C$	R _{IN}	- 10 8.0	4.0 30 -	- - -	kΩ
Input Capacitance	Gain 2 (Note 4)	C _{IN}	-	2.0	-	pF
Input Offset Current	$\begin{array}{l} T_A=25^\circ C\\ 0^\circ C\ \leq\ T_A\ \leq\ 70^\circ C \end{array}$	I _{OS}		0.4 _	5.0 6.0	μΑ
Input Bias Current	$\begin{array}{c} T_A=25^\circ C\\ 0^\circ C \ \leq \ T_A \ \leq \ 70^\circ C \end{array}$	I _{BIAS}		9.0 _	30 40	μΑ
Input Noise Voltage	BW 1.0 kHz to 10 MHz	V _{NOISE}	-	12	-	μV_{RMS}
Input Voltage Range	_	V _{IN}	±1.0	-	-	V
Common-Mode Rejection Ratio Gain 2 (Note 4)	$V_{CM} \pm 1.0 \text{ V}, \text{ f} < 100 \text{ kHz}, \text{ T}_{A} = 25^{\circ}\text{C}$ $V_{CM} \pm 1.0 \text{ V}, \text{ f} < 100 \text{ kHz},$ $0^{\circ}\text{C} \leq \text{T}_{A} \leq 70^{\circ}\text{C}$	CMRR	60 50	86 -		dB
Supply Voltage Rejection Ratio Gain 2 (Note 4)	$V_{CM} \pm 1.0$ V, f < 5.0 MHz $\Delta V_{S} = \pm 0.5$ V	PSRR	50	60 70	-	dB
Output Offset Voltage Gain 1 Gain 2 (Note 4) Gain 3 (Note 5) Gain 3 (Note 5)	$\begin{array}{c} R_{L} = \infty \\ R_{L} = \infty \\ R_{L} = \infty, T_{A} = 25^{\circ}C \\ R_{L} = \infty, 0^{\circ}C \leq T_{A} \leq 70^{\circ}C \end{array}$	V _{OS}	- - - -	- - 0.35 -	1.5 1.5 0.75 1.0	V
Output Common-Mode Voltage	$R_L = \infty$, $T_A = 25^{\circ}C$	V _{CM}	2.4	2.9	3.4	V
Output Voltage Swing Differential	$ \begin{array}{l} R_L = 2.0 \; k\Omega, T_A = 25^{\circ}C \\ R_L = 2.0 \; k\Omega, 0^{\circ}C \leq T_A \leq 70^{\circ}C \end{array} \end{array} $	V _{OUT}	3.0 2.8	4.0 _	-	V
Output Resistance	_	R _{OUT}	-	20	-	Ω
Power Supply Current	$ \begin{array}{l} R_L = \infty, \ T_A = 25^\circ C \\ R_L = \infty, \ 0^\circ C \ \leq \ T_A \ \leq \ 70^\circ C \end{array} $	I _{CC}		18 -	24 27	mA

DC ELECTRICAL CHARACTERISTICS ($V_{SS} = \pm 6.0 \text{ V}$, $V_{CM} = 0$, typicals at $T_A = +25^{\circ}C$, min and max at $0^{\circ}C \le T_A \le 70^{\circ}C$, unless
otherwise noted. Recommended operating supply voltages $V_{S} = \pm 6.0$ V.)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

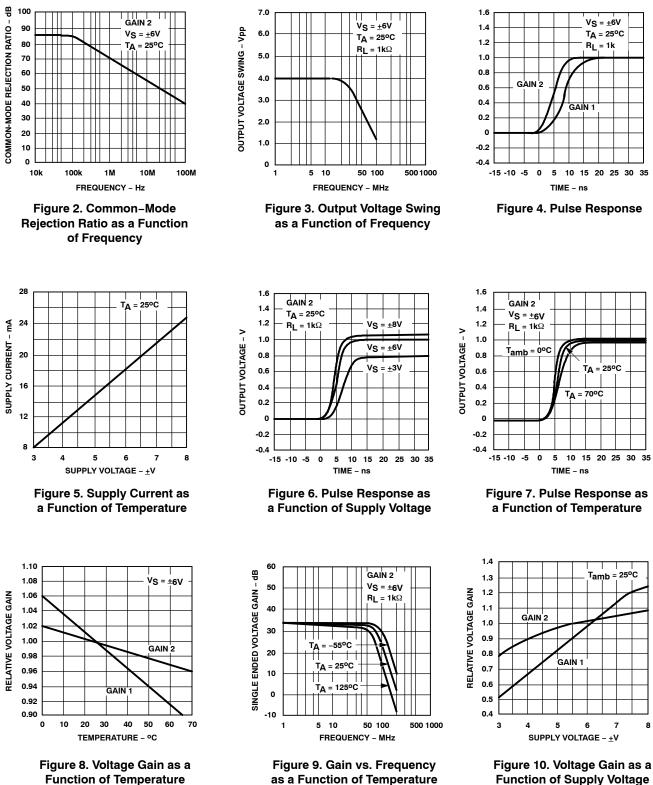
AC ELECTRICAL CHARACTERISTICS (T_A = +25°C V_{SS} = \pm 6.0 V, V_{CM} = 0, unless otherwise noted. Recommended operating

supply voltages V_S = ± 6.0 V.)

Characteristic	Test Conditions	Symbol	Min	Тур	Max	Unit
Bandwidth Gain 1 (Note 2) Gain 2 (Notes 3 and 4)	-	BW		40 90		MHz
Rise Time Gain 1 (Note 2) Gain 2 (Notes 3 and 4)	V _{OUT} = 1.0 V _{P-P}	t _R		10.5 4.5	12 -	ns
Propagation Delay Gain 1 (Note 2) Gain 2 (Notes 3 and 4)	V _{OUT} = 1.0 V _{P-P}	t _{PD}		7.5 6.0	10 -	ns

Gain select Pins G_{1A} and G_{1B} connected together.
 Gain select Pins G_{2A} and G_{2B} connected together.
 Applies to 14-pin version only.
 All gain select pins open.

TYPICAL PERFORMANCE CHARACTERISTICS



Function of Supply Voltage

TYPICAL PERFORMANCE CHARACTERISTICS

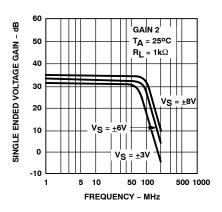


Figure 11. Gain vs. Frequency as a Function of Supply Voltage

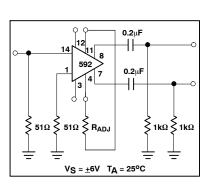


Figure 12. Voltage Gain Adjust Circuit

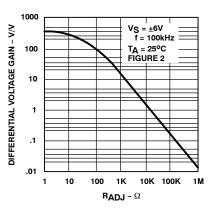


Figure 13. Voltage Gain as a Function of RADJ (Figure 2)

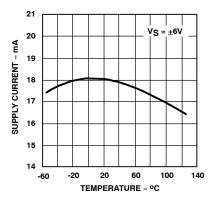


Figure 14. Supply Current as a **Function of Temperature**

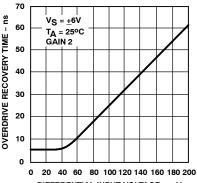


Figure 15. Differential Overdrive **Recovery Time**

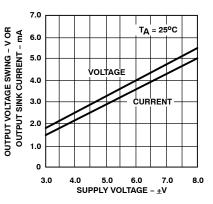
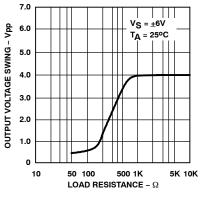
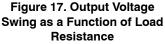


Figure 16. Output Voltage and **Current Swing as a Function of Supply Voltage**





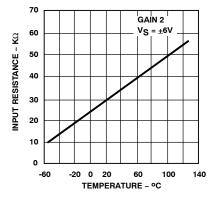
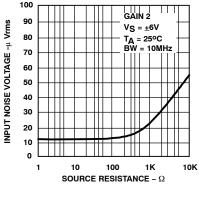
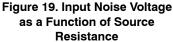
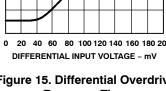


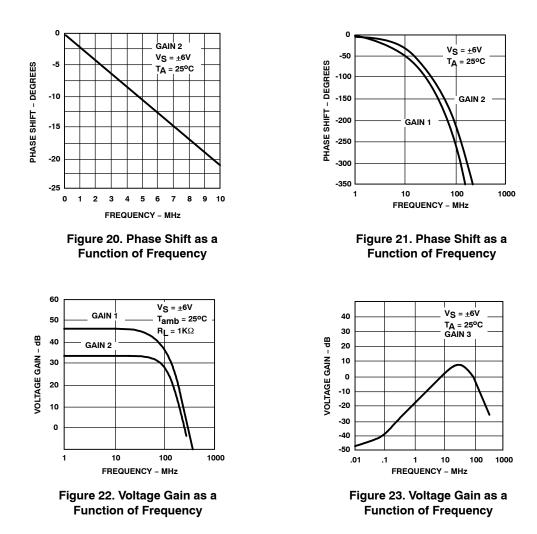
Figure 18. Input Resistance as a **Function of Temperature**







TYPICAL PERFORMANCE CHARACTERISTICS



TEST CIRCUITS ($T_A = 25^{\circ}C$, UNLESS OTHERWISE NOTED.)

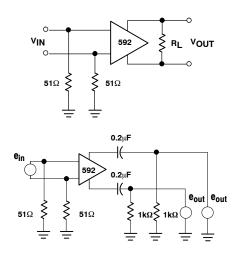
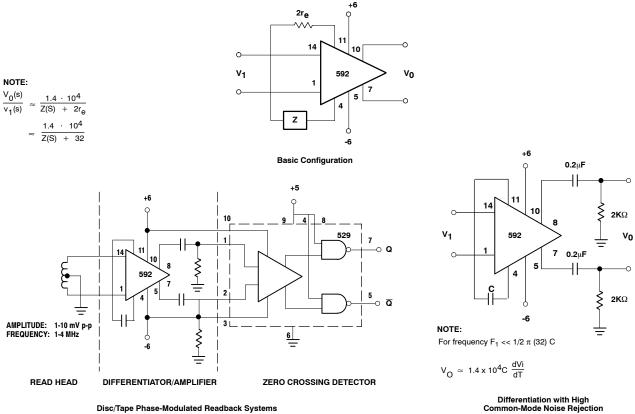
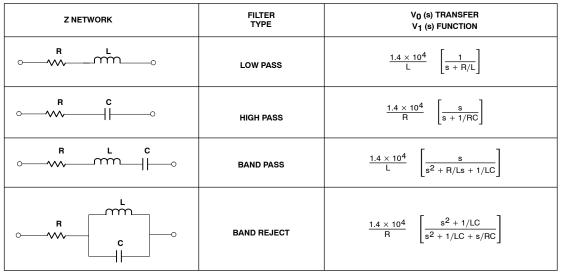


Figure 24. Test Circuits



Disc/Tape Phase-Modulated Readback Systems





NOTES:

In the networks above, the R value used is assumed to include $2r_e$, or approximately 32Ω .

 $S = j\Omega$ $\Omega = 2\pi f$

Figure 26. Filter Networks

ORDERING INFORMATION

Device	Temperature Range	Package	Shipping [†]
NE592D8R2G	0.42	SOIC-8 (Pb-Free)	2500 / Tape & Reel
NE592D14R2G	0 to +70°C	SOIC-14 (Pb-Free)	2500 / Tape & Reel

DISCONTINUED (Note 6)

NE592D8G	0 to +70°C	SOIC-8 (Pb-Free)	98 Units/Rail
NE592D14G	010 +70 C	SOIC-14 (Pb-Free)	55 Units/Rail

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

DISCONTINUED: These devices are not recommended for new design. Please contact your onsemi representative for information. The most current information on these devices may be available on <u>www.onsemi.com</u>.

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*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. COLLECTOR, #2 4 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. 8. CATHODE STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4 SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. **MIRROR 1** STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT 2 OVI 0 UVLO З. 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

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STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE #2 З. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW_TO_GND 2. DASIC OFF DASIC_SW_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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8

COLLECTOR, #1

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